NZQA5V6XV5T1G Series

Quad Array for ESD Protection

This quad monolithic silicon voltage suppressor is designed for applications requiring transient overvoltage protection capability. It is intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment, and other applications. Its quad junction common anode design protects four separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Specification Features

- SOT–553 Package Allows Four Separate Unidirectional Configurations
- Low Leakage < 1 µA @ 3 V for NZQA5V6XV5T1G
- Breakdown Voltage: 5.6 V 6.8 V @ 1 mA
- ESD Protection Meeting IEC61000-4-2 Level 4
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb–Free Devices

Mechanical Characteristics

- Void Free, Transfer-Molded, Thermosetting Plastic Case
- Corrosion Resistant Finish, Easily Solderable
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- 100% Lead Free, MSL1 @ 260°C Reflow Temperature



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SOT-553 CASE 463B

MARKING DIAGRAM

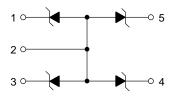


xx = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)



ORDERING INFORMATION

Device	Package	Shipping [†]
NZQA5V6XV5T1G	SOT-553 (Pb-Free)	4000 / Tape & Reel
NZQA5V6XV5T3G	SOT-553 (Pb-Free)	16000 / Tape & Reel
NZQA6V2XV5T1G	SOT-553 (Pb-Free)	4000 / Tape & Reel
NZQA6V8XV5T1G	SOT-553 (Pb-Free)	4000 / Tape & Reel
SZQA6V8XV5T1G	SOT-553 (Pb-Free)	4000 / Tape & Reel

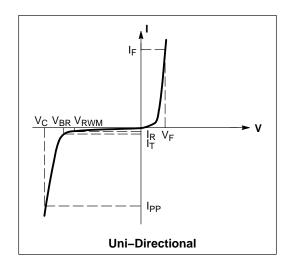
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NZQA5V6XV5T1G Series

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V_{BR}	Breakdown Voltage @ I _T
I _T	Test Current
ΘV_{BR}	Maximum Temperature Coefficient of V _{BR}
I _F	Forward Current
V _F	Forward Voltage @ I _F
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}
I _{ZK}	Reverse Current
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}



MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

	Characteristic	Symbol	Value	Unit
Peak Power Dissipation	on (8 X 20 μs @ T _A = 25°C) (Note 1)	P _{PK}	100	W
Steady State Power -	1 Diode (Note 2)	P _D	300	mW
Thermal Resistance Junction to Ambient Above 25°C, Derate		$R_{ hetaJA}$	370 2.7	°C/W mW/°C
Maximum Junction Temperature		T _{Jmax}	150	°C
Operating Junction and Storage Temperature Range		T _J T _{stg}	-55 to +150	°C
ESD Discharge MIL STD 883C – Method 3015–6 IEC1000–4–2, Air Discharge IEC1000–4–2, Contact Discharge		V _{PP}	16 30 30	kV
Lead Solder Tempera	ture (10 seconds duration)	T_L	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS $(T_A = 25^{\circ}C)$

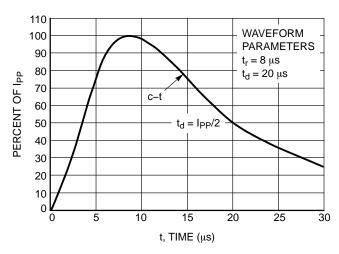
	Device	Breakdown Voltage V _{BR} @ 1 mA (Volts)		Leakage Current I _{RM} @ V _{RM} V _C Max @ I _{PP}		Typ Capacitance @ 0 V Bias (Note 3)	Max V _F @ I _F = 200 mA			
Device*	Marking	Min	Nom	Max	V _{RWM}	I _{RWM} (μA)	V _C (V)	I _{PP} (A)	(pF)	(V)
NZQA5V6XV5T1G	56	5.32	5.6	5.88	3.0	1.0	10.5	10	90	1.3
NZQA6V2XV5T1G	62	5.89	6.2	6.51	4.0	0.5	11.5	9.0	80	1.3
NZQA6V8XV5T1G	68	6.46	6.8	7.14	4.3	0.1	12.5	8.0	70	1.3

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. *Includes SZ-prefix devices where applicable.

- Non-repetitive current per Figure 1.
 Only 1 diode under power. For all 4 diodes under power, P_D will be 25%. Mounted on FR-4 board with min pad.
 Capacitance of one diode at f = 1 MHz, V_R = 0 V, T_A = 25°C

NZQA5V6XV5T1G Series

TYPICAL CHARACTERISTICS



% OF RATED POWER OR IPP ō T_A, AMBIENT TEMPERATURE (°C)

Figure 1. Pulse Waveform

Figure 2. Power Derating Curve

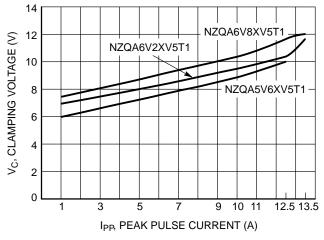


Figure 3. Clamping Voltage versus Peak Pulse Current

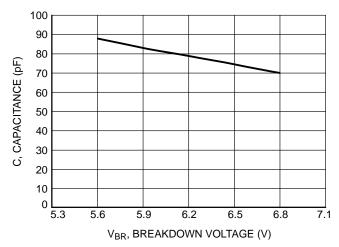
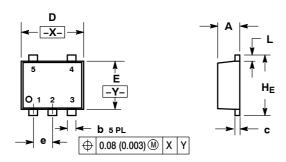


Figure 4. Typical Capacitance

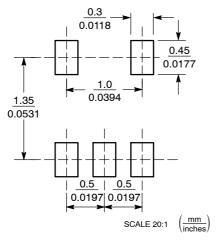


SOT-553, 5 LEAD CASE 463B **ISSUE C**

DATE 20 MAR 2013



RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETERS

 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS: MINIMUM LEAD THICKNESS IS THE MINIMUM
 THICKNESS OF BASE MATERIAL.

	M	ILLIMETE	RS		INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.13	0.18	0.003	0.005	0.007
D	1.55	1.60	1.65	0.061	0.063	0.065
E	1.15	1.20	1.25	0.045	0.047	0.049
е		0.50 BSC			0.020 BSC	
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.55	1.60	1.65	0.061	0.063	0.065

GENERIC MARKING DIAGRAM*



XX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 1 5. COLLECTOR 2/BASE 1	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	

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PAGE 2 OF 2

ISSUE	REVISION	DATE
Α	ADDED STYLES 3-9. REQ. BY D. BARLOW	11 NOV 2003
В	ADDED NOMINAL VALUES AND UPDATED GENERIC MARKING DIAGRAM. REQ. BY HONG XIAO	27 MAY 2005
С	UPDATED DIMENSIONS D, E, AND HE. REQ. BY J. LETTERMAN.	20 MAR 2013

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